

UNISONIC TECHNOLOGIES CO., LTD

TGBR3S100

TRENCH MOS SCHOTTKY BARRIER RECTIFIER

DESCRIPTION

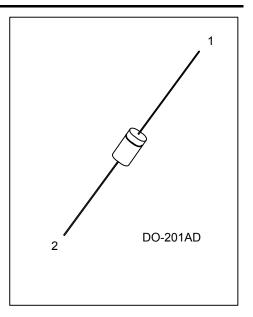
The UTC **TGBR3S100** is a trench mos schottky barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

■ FEATURES

- * Super low forward voltage drop
- * High switching speed



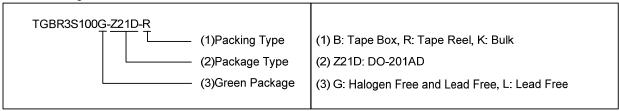




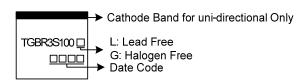
ORDERING INFORMATION

Ordering Number		Packago	Pin Assignment		Dooking	
Lead Free	Halogen Free	Package	1	2	Packing	
TGBR3S100L-Z21D-B	TGBR3S100G-Z21D-B	DO-201AD	K	Α	Tape Box	
TGBR3S100L-Z21D-R	TGBR3S100G-Z21D-R	DO-201AD	K	Α	Tape Reel	
TGBR3S100L-Z21D-K	TGBR3S100G-Z21D-K	DO-201AD	K	Α	Bulk	

Note: Pin Assignment: K: Cathode A: Anode



MARKING



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TGBR3S100 DIODE

■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage	V_{RM}	100	V
Working Peak Reverse Voltage	V_{RWM}	100	V
Peak Repetitive Reverse Voltage	V_{RRM}	100	V
Average Rectified Output Current	Io	3	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	130	Α
Operating Junction Temperature	TJ	-65 ~ + 150	Ŝ
Storage Temperature	T _{STG}	-65 ~ + 150	Ĉ

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS (PER LEG)

PARAMETER	SYMBOL	RATINGS	UNIT
Typical Thermal Resistance	θ_{JC}	22	°C/W

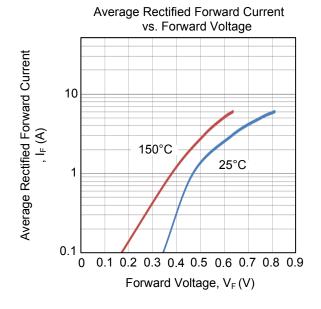
■ ELECTRICAL CHARACTERISTICS (PER LEG) (T_A =25°C, unless otherwise specified.)

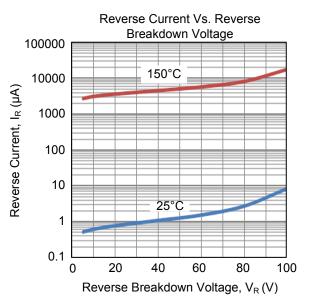
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage	$V_{(BR)R}$	I _R =0.5mA	100			V
Forward Voltage Drop	, ,	I _F =1A, T _J =25°C			0.60	V
		I _F =1A, T _J =150°C			0.48	V
	V	I _F =3A, T _J =25°C			0.80	V
	V_{FM}	I _F =3A, T _J =150°C			0.65	V
		I _F =5A, T _J =25°C			0.93	V
		I _F =5A, T _J =150°C			0.60 0.48 0.80 0.65 0.93 0.75 10.5 22	V
Leakage Current		V _R =100V, T _J =25°C			10.5	μΑ
	I _{RM}	V _R =100V, T _J =150°C			22	mA
Reverse Recovery Time	t _{rr}	I _F =3A, di/dt=100A/μs, V _R =100V		28		ns

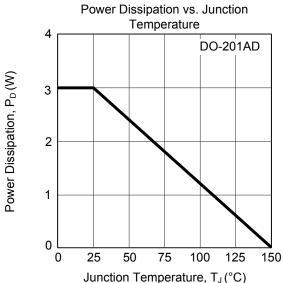
Note: Pulse Test: Pulse width ≤ 300µs, Duty cycle ≤ 2%.

TGBR3S100 DIODE

■ TYPICAL CHARACTERISTICS







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